

# NCERT CLASS XII PHYSICS – FORMULA SHEET

## Chapter 1: Electric Charges and Fields

<b>Coulomb's Law</b>	$F = \frac{1}{4\pi\epsilon_0} \frac{q_1 q_2}{r^2}$
<b>Electric Field</b>	$\vec{E} = \frac{\vec{F}}{q}$ $E = \frac{1}{4\pi\epsilon_0} \frac{q}{r^2}$
<b>Electric Field due to Continuous Charge of Line charge:</b>	$E = \frac{\lambda}{2\pi\epsilon_0 r}$
<b>Electric Field due to Continuous Charge of Infinite plane sheet:</b>	$E = \frac{\sigma}{2\epsilon_0}$
<b>Gauss's Law</b>	$\oint \vec{E} \cdot d\vec{A} = \frac{Q_{\text{enclosed}}}{\epsilon_0}$
<b>Electric Dipole</b>	$\vec{p} = q\vec{d}$ $\tau = pE \sin \theta$ $U = -pE \cos \theta$

## Chapter 2: Electrostatic Potential and Capacitance

Electric Potential	$V = \frac{W}{q}$ $V = \frac{1}{4\pi\epsilon_0} \frac{q}{r}$
Relation between E and V	$\vec{E} = -\nabla V$ <p>(Along x-axis: <math>E = -\frac{dV}{dx}</math>)</p>
Potential due to Dipole (axial)	$V = \frac{1}{4\pi\epsilon_0} \frac{p}{r^2}$
Potential Energy	$U = qV$
Capacitance	$C = \frac{Q}{V}$
Capacitors	$C_{\text{eq}} = C_1 + C_2 + \dots$
<ul style="list-style-type: none"> <li>Parallel combination:</li> <li>Series combination:</li> </ul>	$\frac{1}{C_{\text{eq}}} = \frac{1}{C_1} + \frac{1}{C_2}$

## Chapter 3: Current Electricity

Current	$I = \frac{dq}{dt}$
Ohm's Law	$V = IR$
Resistance	$R = \rho \frac{l}{A}$
Resistance Temperature Dependence	$R = R_0(1 + \alpha T)$
Drift Velocity	$v_d = \frac{I}{nqA}$ $v_d = \mu E$
Mobility	$\mu = \frac{q\tau}{m}$
Current Density	$\vec{J} = nq\vec{v}_d$ $\vec{J} = \sigma \vec{E}$
Conductivity	$\sigma = \frac{1}{\rho} = \frac{nq^2\tau}{m}$
Electrical Power	$P = VI = I^2R = \frac{V^2}{R}$

## Chapter 4: Moving Charges and Magnetism

<b>Lorentz Force</b>	$\vec{F} = q(\vec{E} + \vec{v} \times \vec{B})$
<b>Force on Current-Carrying Conductor</b>	$F = BIl \sin \theta$
<b>Magnetic Field due to Straight Conductor</b>	$B = \frac{\mu_0 I}{2\pi r}$
<b>Magnetic Field due to Circular Loop (center)</b>	$B = \frac{\mu_0 I}{2R}$ (with N turns: $B = \frac{\mu_0 NI}{2R}$ )
<b><i>Motion of Charged Particle in Magnetic Field</i></b>	
• <b>Radius:</b>	$r = \frac{mv}{qB}$
• <b>Time period:</b>	$T = \frac{2\pi m}{qB}$
• <b>Frequency:</b>	$f = \frac{qB}{2\pi m}$
<b>Helical Path</b>	$r = \frac{mv \sin \theta}{qB}$ Pitch = $v \cos \theta \cdot T$
<b>Solenoid</b>	$B = \mu_0 n I$
<b>Magnetic Energy Density</b>	$u = \frac{B^2}{2\mu_0}$

## Chapter 5: Magnetism and Matter

<b>Magnetic Dipole Moment</b>	$m = IA$
<b>Torque on Magnetic Dipole</b>	$\tau = mB \sin \theta$
<b>Magnetic Potential Energy</b>	$U = -mB \cos \theta$
<b>Magnetisation</b>	$M = \frac{\text{Magnetic moment}}{\text{Volume}}$
<b>Magnetic Susceptibility</b>	$\chi = \frac{M}{H}$
<b>Relation between B, H, and M</b>	$B = \mu_0(H + M)$
<b>Relative Permeability</b>	$\mu_r = 1 + \chi$
<i>Hall Effect</i> <b>Hall Voltage</b>	$V_H = \frac{IB}{nqt}$

### Constants Used

$$\epsilon_0 = 8.85 \times 10^{-12} \text{ C}^2\text{N}^{-1}\text{m}^{-2}$$

$$\mu_0 = 4\pi \times 10^{-7} \text{ T}\cdot\text{m/A}$$

$$e = 1.6 \times 10^{-19} \text{ C}$$

## Chapter 6: Electromagnetic Induction

<b>Magnetic Flux</b>	$\Phi_B = \vec{B} \cdot \vec{A} = BA \cos \theta$
<b>Faraday's Laws</b>	$\mathcal{E} = -\frac{d\Phi_B}{dt}$ (Negative sign $\rightarrow$ Lenz's law)
<b>Induced EMF (N turns)</b>	$\mathcal{E} = -N \frac{d\Phi}{dt}$
<b>Motional EMF</b>	$\mathcal{E} = Blv$
<b>Induced Current</b>	$I = \frac{\mathcal{E}}{R}$
<b>Self-Inductance</b>	$\mathcal{E} = -L \frac{dI}{dt}$
<b>Self-Inductance of Solenoid</b>	$L = \mu_0 \frac{N^2 A}{l}$
<b>Mutual Inductance</b>	$\mathcal{E}_2 = -M \frac{dI_1}{dt}$
<b>Energy Stored in Inductor</b>	$U = \frac{1}{2} LI^2$
<b>Energy Density of Magnetic Field</b>	$u = \frac{B^2}{2\mu_0}$

## Chapter 7: Alternating Current

<b>AC Voltage / Current</b>	$v = v_0 \sin \omega t$ $i = i_0 \sin(\omega t + \phi)$
<b>RMS Values</b>	$V_{\text{rms}} = \frac{V_0}{\sqrt{2}}$ $I_{\text{rms}} = \frac{I_0}{\sqrt{2}}$
<b>Reactance</b> • Inductive:	$X_L = \omega L$
<b>Reactance</b> • Capacitive:	$X_C = \frac{1}{\omega C}$
<b>Impedance (LCR Circuit)</b>	$Z = \sqrt{R^2 + (X_L - X_C)^2}$
<b>Current in AC Circuit</b>	$I_{\text{rms}} = \frac{V_{\text{rms}}}{Z}$
<b>Phase Angle</b>	$\tan \phi = \frac{X_L - X_C}{R}$
<b>Power in AC Circuit</b>	$P = V_{\text{rms}} I_{\text{rms}} \cos \phi$
<b>Power Factor</b>	$\cos \phi = \frac{R}{Z}$
<b>Resonance Condition</b>	$X_L = X_C$ $\omega_0 = \frac{1}{\sqrt{LC}}$
<b>Quality Factor</b>	$Q = \frac{\omega_0 L}{R}$

## Chapter 8: Electromagnetic Waves

Speed of EM Wave	$c = \frac{1}{\sqrt{\mu_0 \epsilon_0}}$
Relation between E and B	$E = cB$
Energy Density	$u = \frac{1}{2} \epsilon_0 E^2 + \frac{1}{2} \frac{B^2}{\mu_0}$
Intensity of EM Wave	$I = \frac{1}{2} c \epsilon_0 E_0^2$

### EM Spectrum (Order)

Radio → Microwave → Infrared → Visible → UV → X-ray → Gamma

(No numericals beyond these relations in NCERT)



## Chapter 9: Ray Optics and Optical Instruments

<b>Mirror Formula</b>	$\frac{1}{f} = \frac{1}{v} + \frac{1}{u}$
<b>Magnification (Mirror)</b>	$m = \frac{h_i}{h_o} = -\frac{v}{u}$
<b>Refraction (Snell's Law)</b>	$n_1 \sin i = n_2 \sin r$
<b>Refractive Index</b>	$n = \frac{c}{v}$
<b>Apparent Depth</b>	$\text{Apparent depth} = \frac{\text{Real depth}}{n}$
<b>Lens Formula</b>	$\frac{1}{f} = \frac{1}{v} - \frac{1}{u}$
<b>Magnification (Lens)</b>	$m = \frac{v}{u}$
<b>Power of Lens</b>	$P = \frac{1}{f(\text{in m})}$
<b>Combination of Lenses</b>	$P_{\text{eq}} = P_1 + P_2$
<b>Total Internal Reflection</b>	$\sin C = \frac{1}{n}$
<i>Microscope Magnifying Power</i> • <b>Normal adjustment:</b>	$M = \frac{D}{f}$
<b>Telescope Magnifying Power</b>	$M = \frac{f_o}{f_e}$

## Chapter 10: Wave Optics

<b>Wave Equation</b>	$v = f\lambda$
<b>Superposition Principle</b>	$y = y_1 + y_2$
<b>Young's Double Slit Experiment (YDSE)</b>	
• <b>Path Difference:</b>	$\Delta x = \frac{xd}{D}$
• <b>Fringe Width:</b>	$\beta = \frac{\lambda D}{d}$
• <b>Maxima Condition:</b>	$\Delta = n\lambda$
• <b>Minima Condition:</b>	$\Delta = (2n + 1)\frac{\lambda}{2}$
<b>Intensity Relation</b>	$I = I_1 + I_2 + 2\sqrt{I_1 I_2} \cos \phi$
<b>Diffraction (Single Slit)</b>	$a \sin \theta = n\lambda$
<b>Polarisation</b> ( <i>Malus' Law</i> )	$I = I_0 \cos^2 \theta$
<b>Brewster's Law</b>	$\tan i_B = n$

## Chapter 11: Dual Nature of Radiation and Matter

<b>Photon Energy</b>	$E = h\nu = \frac{hc}{\lambda}$
<b>Photoelectric Equation (Einstein)</b>	$h\nu = \phi + K_{\max}$
<b>Maximum Kinetic Energy</b>	$K_{\max} = h\nu - \phi$
<b>Stopping Potential</b>	$eV_0 = K_{\max}$
<b>Threshold Frequency</b>	$\nu_0 = \frac{\phi}{h}$
<b>De Broglie Wavelength</b>	$\lambda = \frac{h}{p} = \frac{h}{mv}$
<b>De Broglie Wavelength (Electron accelerated by V)</b>	$\lambda = \frac{h}{\sqrt{2meV}}$ <p>(Relativistic correction, if needed in difficult problems):</p> $\lambda = \frac{h}{\sqrt{2meV \left(1 + \frac{eV}{2mc^2}\right)}}$

## Chapter 12: Atoms

Bohr Radius	$r_n = \frac{n^2 h^2 \epsilon_0}{\pi m e^2}$
Radius of nth Orbit (Hydrogen)	$r_n = n^2 a_0$
Velocity of Electron	$v_n = \frac{e^2}{2\epsilon_0 h n}$
Total Energy of Electron	$E_n = -\frac{13.6}{n^2} \text{ eV}$
Energy Difference	$\Delta E = E_{n_2} - E_{n_1}$
Frequency of Emitted Radiation	$h\nu = E_{n_2} - E_{n_1}$
Rydberg Formula	$\frac{1}{\lambda} = R \left( \frac{1}{n_1^2} - \frac{1}{n_2^2} \right)$ <p>Where:</p> $R = 1.097 \times 10^7 \text{ m}^{-1}$

## Chapter 13: Nuclei

<b>Nuclear Radius</b>	$R = R_0 A^{1/3}$
<b>Mass Defect</b>	$\Delta m = Zm_p + (A - Z)m_n - m_{\text{nucleus}}$
<b>Binding Energy</b>	$BE = \Delta mc^2$
<b>Binding Energy per Nucleon</b>	$\frac{BE}{A}$
<b>Radioactive Decay Law</b>	$N = N_0 e^{-\lambda t}$
<b>Activity</b>	$A = \lambda N$
<b>Half-Life</b>	$T_{1/2} = \frac{\ln 2}{\lambda}$
<b>Mean Life</b>	$\tau = \frac{1}{\lambda}$
<b>Relation</b>	$\tau = \frac{T_{1/2}}{0.693}$
<b>Q-Value of Nuclear Reaction</b>	$Q = (\text{Mass of reactants} - \text{Mass of products})c^2$

## Chapter 14: Semiconductor Electronics

<b>Drift Velocity</b>	$v_d = \mu E$
<b>Mobility</b>	$\mu = \frac{e\tau}{m}$
<b>Conductivity</b>	$\sigma = ne\mu$
<b>Resistivity</b>	$\rho = \frac{1}{\sigma}$
<b>Current Density</b>	$J = \sigma E$
<b>Intrinsic Carrier Concentration</b>	$n_e = n_h = n_i$
<b>Relation in Semiconductor</b>	$np = n_i^2$
<b>Diode Equation</b>	$I = I_0 \left( e^{\frac{V}{V_T}} - 1 \right)$ <p>Where:</p> $V_T = \frac{kT}{e}$
<b>Zener Breakdown Voltage</b>	$V_Z = \text{constant (device property)}$
<b>Rectifier Efficiency</b>	$\eta = \frac{P_{dc}}{P_{ac}}$
<b>Ripple Factor</b>	$r = \frac{\text{rms value of ac component}}{\text{dc value}}$
<b>Logic Gates (Basic Relations)</b>	<ul style="list-style-type: none"> <li>• AND: <math>Y = A \cdot B</math></li> <li>• OR: <math>Y = A + B</math></li> <li>• NOT: <math>Y = \bar{A}</math></li> </ul>

### Important Constants

$$h = 6.63 \times 10^{-34} \text{ J}\cdot\text{s}$$

$$e = 1.6 \times 10^{-19} \text{ C}$$

$$m_e = 9.1 \times 10^{-31} \text{ kg}$$

$$c = 3 \times 10^8 \text{ m/s}$$